

APBD3224LSURKCGKC

3.2 x 2.4 mm SMD Chip LED Lamp

DESCRIPTIONS

- The Hyper Red source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- · The Green source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- · Electrostatic discharge and power surge could damage the LEDs
- . It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- · All devices, equipments and machineries must be electrically grounded

FEATURES

- 3.2 x 2.4 mm SMD LED, 2.4 mm thickness
- Low power consumption
- · Ideal for backlight and indicator
- Package: 1500 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- RoHS compliant

APPLICATIONS

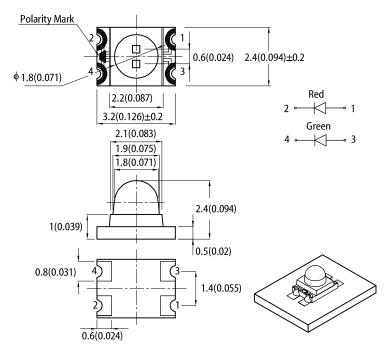
- Backlight
- · Status indicator
- · Home and smart appliances
- · Wearable and portable devices
- · Healthcare applications

ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices

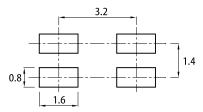


PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units: mm; tolerance: \pm 0.1)



- Notes:
 1. All dimensions are in millimeters (inches).
 2. Tolerance is ±0.1(0.004") unless otherwise noted.
- The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

 The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color	Long Type	Iv (mcd) @ 2mA [2]		Viewing Angle [1]	
	(Material)	Lens Type	Min.	Тур.	201/2	
APBD3224LSURKCGKC	■ Hyper Red (AlGaInP)	- Water Clear	20	50		
			*10	*30	20°	
	☐ Green (AlGaInP)		10	30	20	
			*10	*30		

Notes.

1. 61/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

2. Luminous intensity / luminous flux: +/-15%.

* Luminous intensity value is traceable to CIE127-2007 standards.





ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value			Unit
Parameter			Min.	Тур.	Max.	Unit
Wavelength at Peak Emission I _F = 2mA	λ_{peak}	Hyper Red Green	-	645 574	-	nm
Dominant Wavelength I _F = 2mA	λ _{dom} ^[1]	Hyper Red Green	-	630 570	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 2mA	Δλ	Hyper Red Green	-	28 20	-	nm
Forward Voltage I _F = 2mA	V _F ^[2]	Hyper Red Green	1.5 1.5	1.75 1.9	2.1 2.1	V
Reverse Current (V _R = 5V)	I _R	Hyper Red Green	-	-	10 10	μА
Temperature Coefficient of λ_{peak} $I_F=2mA,$ -10°C $\leq T \leq 85^{\circ}C$	TC_{\lambdapeak}	Hyper Red Green	-	0.14 0.12	-	nm/°C
Temperature Coefficient of λ_{dom} $I_F=2mA,$ -10°C $\leq T \leq 85^{\circ}C$	TC_{\lambdadom}	Hyper Red Green	-	0.05 0.08	-	nm/°C
Temperature Coefficient of V_F $I_F = 2mA$, $-10^{\circ}C \le T \le 85^{\circ}C$	TC _V	Hyper Red Green	-	-1.9 -1.9	-	mV/°C

Notes:

1. The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd:±1nm.)
2. Forward voltage:±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

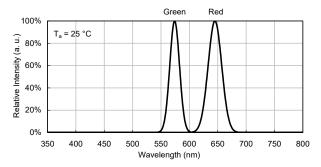
Parameter	Comple el	Va	l lmi4		
Parameter	Symbol	Hyper Red	Green	Unit	
Power Dissipation	P _D	75	75	mW	
Reverse Voltage	V_R	5	5	V	
Junction Temperature	TJ	115	115	°C	
Operating Temperature	T _{op}	-40 Ti	°C		
Storage Temperature	T _{stg}	-40 T	°C		
DC Forward Current	I _F	30	30	mA	
Peak Forward Current	I _{FP} ^[1]	185	150	mA	
Electrostatic Discharge Threshold (HBM)	-	3000	3000	V	
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	660	670	°C/W	
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	560	580	°C/W	

Notes:
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. $R_{\text{Ib.Ja}}$, $R_{\text{Rb.Ja}}$, R_{Bulls} from mounting on PC board FR4 (pad size \geq 16 mm² per pad).
3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.



TECHNICAL DATA

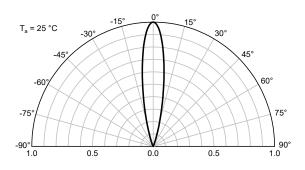
RELATIVE INTENSITY vs. WAVELENGTH

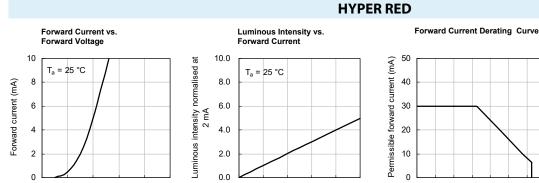


2.0

Forward voltage (V)

SPATIAL DISTRIBUTION

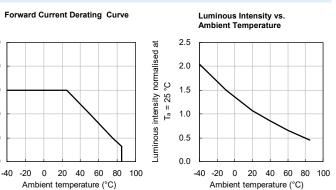




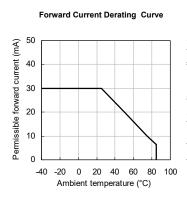
Forward current (mA)

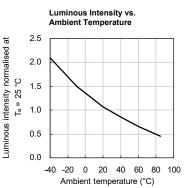
0

10



GREEN Forward Current vs. Luminous Intensity vs. Forward Voltage 10 10.0 Luminous intensity normalised at 2 mA T_a = 25 °C T_a = 25 °C 8 8.0 Forward current (mA) 6 6.0 4.0 2 2.0 0.0 0 10 1.8 1.9 2.0 2.1 Forward voltage (V) Forward current (mA)

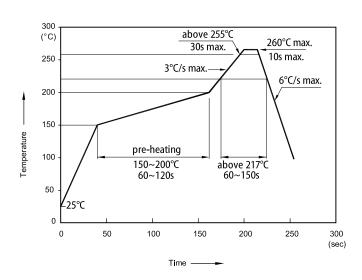




1.6 1.7 1.8 1.9

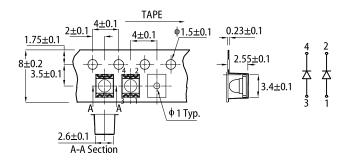


REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS

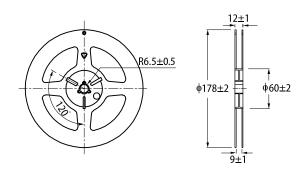


- 1. Don't cause stress to the LEDs while it is exposed to high temperature.
 2. The maximum number of reflow soldering passes is 2 times.
 3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

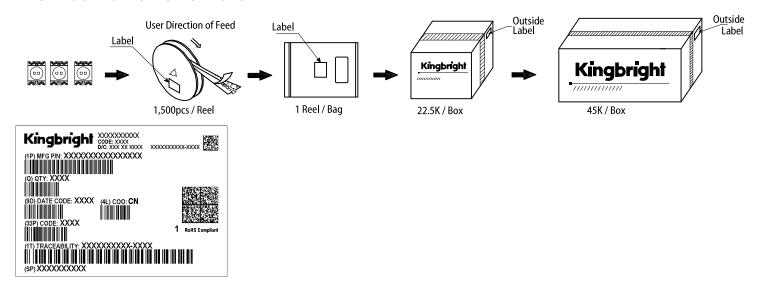
TAPE SPECIFICATIONS (units:mm)



REEL DIMENSION (units: mm)



PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.

 The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening
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